Selection Guide

	CY7C164-15 CY7C166-15	CY7C164-25 CY7C166-25
Maximum Access Time (ns)	15	25
Maximum Operating Current (mA)	115	105
Maximum CMOS Standby Current (mA)	20	20

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature ..... –65°C to +150°C

Ambient Temperature with Power Applied..... –55°C to +125°C

Supply Voltage to Ground Potential ..... –0.5V to +7.0V

DC Voltage Applied to Outputs in High Z State[1] ..... –0.5V to +7.0V

DC Input Voltage[1]..... –0.5V to +7.0V

Output Current into Outputs (LOW)..... 20 mA

Static Discharge Voltage..... >2001V (per MIL-STD-883, Method 3015)

Latch-Up Current ..... >200 mA

Operating Range

Range	Ambient Temperature	V_{CC}
Commercial	0°C to +70°C	5V ± 10%

Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions	–15		–25		Unit
			Min.	Max.	Min.	Max.	
V_{OH}	Output HIGH Voltage	V_{CC} = Min., I_{OH} = –4.0 mA	2.4		2.4		V
V_{OL}	Output LOW Voltage	V_{CC} = Min., I_{OL} = 8.0 mA		0.4		0.4	V
V_{IH}	Input HIGH Voltage		2.2	V_{CC}	2.2	V_{CC}	V
V_{IL}	Input LOW Voltage[1]		–0.5	0.8	–0.5	0.8	V
I_{IX}	Input Leakage Current	GND ≤ V_I ≤ V_{CC}	–5	+5	–5	+5	µA
I_{OZ}	Output Leakage Current	GND ≤ V_O ≤ V_{CC}, Output Disabled	–5	+5	–5	+5	µA
I_{CC}	V_{CC} Operating Supply Current	V_{CC} = Max., I_{OUT} = 0 mA		115		105	mA
I_{SB1}	Automatic $\overline{CE}$ Power-Down Current[2]	Max. V_{CC}, $\overline{CE}$ ≥ V_{IH}, Min. Duty Cycle = 100%		40		20	mA
I_{SB2}	Automatic $\overline{CE}$ Power-Down Current[2]	Max. V_{CC}, $\overline{CE}$ ≥ V_{CC} – 0.3V, V_{IN} ≥ V_{CC} – 0.3V or V_{IN} ≤ 0.3V		20		20	mA

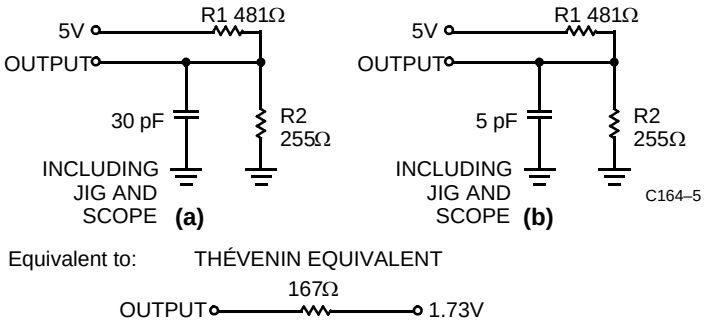
Capacitance[3]

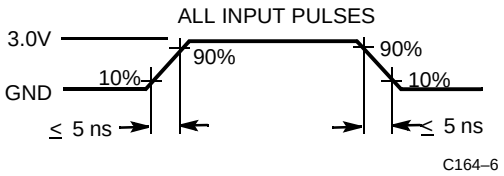
Parameter	Description	Test Conditions	Max.	Unit
C_{IN}	Input Capacitance	T_A = 25°C, f = 1 MHz, V_{CC} = 5.0V	10	pF
C_{OUT}	Output Capacitance		10	pF

Notes:
1. Minimum voltage is equal to –3.0V for pulse durations less than 30 ns.
2. A pull-up resistor to V_{CC} on the $\overline{CE}$ input is required to keep the device deselected during V_{CC} power-up, otherwise I_{SB} will exceed values given.
3. Tested initially and after any design or process changes that may affect these parameters.

Downloaded from Arrow.com.
[+] Feedback

AC Test Loads and Waveforms





Switching Characteristics Over the Operating Range[4]

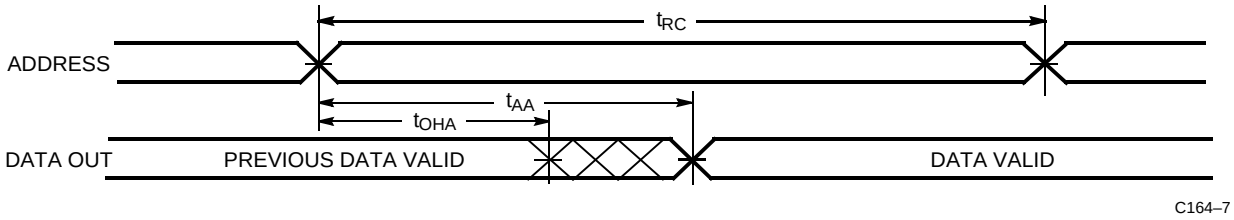
Parameter	Description		CY7C164-15 CY7C166-15 Min.	CY7C164-15 CY7C166-15 Max.	CY7C164-25 CY7C166-25 Min.	CY7C164-25 CY7C166-25 Max.	Unit
READ CYCLE							
t_{RC}	Read Cycle Time		15		25		ns
t_{AA}	Address to Data Valid			15		25	ns
t_{OHA}	Output Hold from Address Change		3		5		ns
t_{ACE}	$\overline{CE}$ LOW to Data Valid			15		25	ns
t_{DOE}	$\overline{OE}$ LOW to Data Valid	7C166		10		12	ns
t_{LZOE}	$\overline{OE}$ LOW to Low Z	7C166	3		3		ns
t_{HZOE}	$\overline{OE}$ HIGH to High Z	7C166		8		10	ns
t_{LZCE}	$\overline{CE}$ LOW to Low Z[5]		3		5		ns
t_{HZCE}	$\overline{CE}$ HIGH to High Z[5, 6]			8		10	ns
t_{PU}	$\overline{CE}$ LOW to Power-Up		0		0		ns
t_{PD}	$\overline{CE}$ HIGH to Power-Down			15		20	ns
WRITE CYCLE[7]							
t_{WC}	Write Cycle Time		15		20		ns
t_{SCE}	$\overline{CE}$ LOW to Write End		12		20		ns
t_{AW}	Address Set-Up to Write End		12		20		ns
t_{HA}	Address Hold from Write End		0		0		ns
t_{SA}	Address Set-Up to Write Start		0		0		ns
t_{PWE}	$\overline{WE}$ Pulse Width		12		15		ns
t_{SD}	Data Set-Up to Write End		10		10		ns
t_{HD}	Data Hold from Write End		0		0		ns
t_{LZWE}	$\overline{WE}$ HIGH to Low Z[5]		5		5		ns
t_{HZWE}	$\overline{WE}$ LOW to High Z[5, 6]			7		7	ns

Notes:
4. Test conditions assume signal transition time of 5 ns or less, timing reference levels of 1.5V, input pulse levels of 0 to 3.0V, and output loading of the specified I_{OL}/I_{OH} and 30-pF load capacitance.
5. At any given temperature and voltage condition, t_{HZCE} is less than t_{LZCE} for any given device. These parameters are guaranteed by design and not 100% tested.
6. t_{HZCE} and t_{HZWE} are specified with C_L = 5 pF as in part (b) in AC Test Loads. Transition is measured ±500 mV from steady-state voltage.
7. The internal write time of the memory is defined by the overlap of $\overline{CE}$ LOW and $\overline{WE}$ LOW. Both signals must be LOW to initiate a write and either signal can terminate a write by going HIGH. The data input set-up and hold timing should be referenced to the rising edge of the signal that terminates the write.

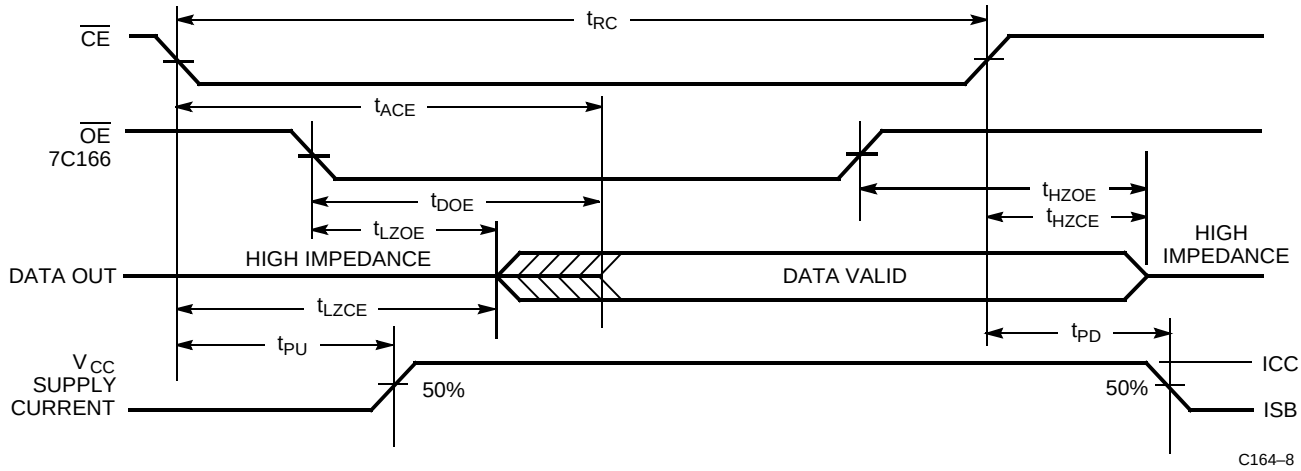
Downloaded from Arrow.com.
[+] Feedback

Switching Waveforms

Read Cycle No. 1[8,9]



Read Cycle No. 2[8,10]

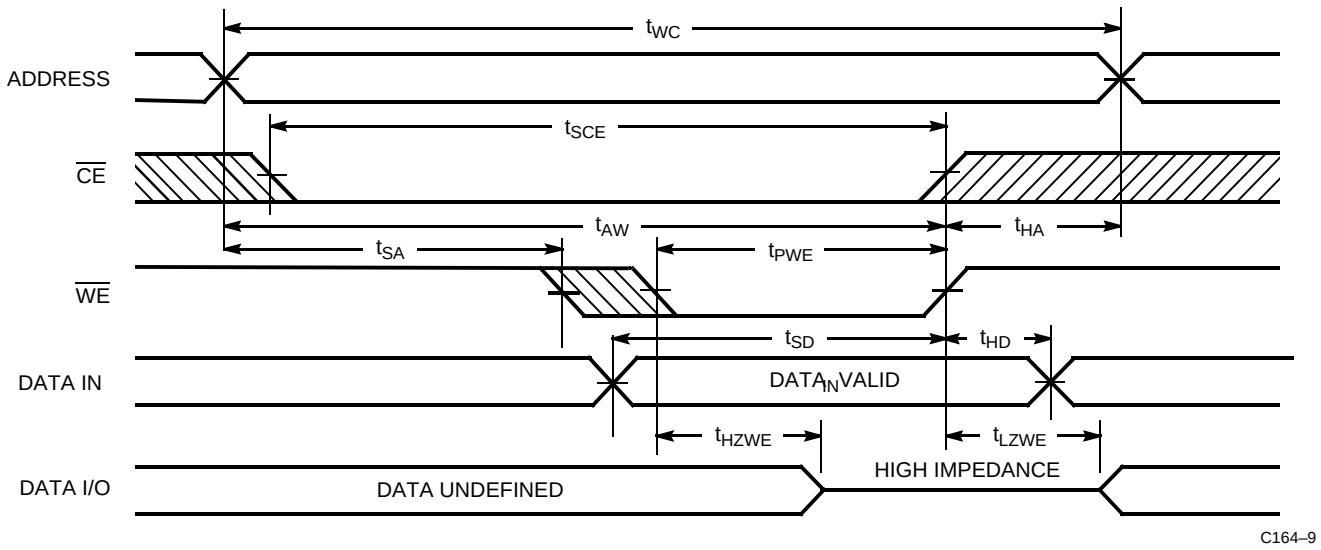


Notes:
8. $\overline{WE}$ is HIGH for read cycle.
9. Device is continuously selected, $\overline{CE} = V_{IL}$. (CY7C166: $\overline{OE} = V_{IL}$ also).
10. Address valid prior to or coincident with $\overline{CE}$ transition LOW.

Downloaded from Arrow.com.
[+] Feedback

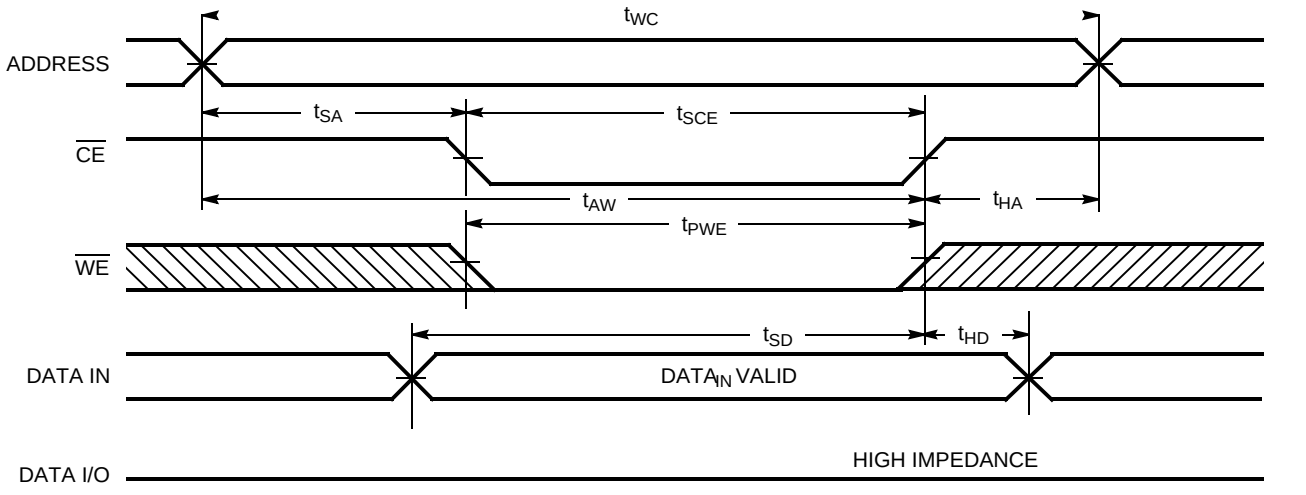
Switching Waveforms (continued)

Write Cycle No. 1($\overline{WE}$ Controlled)[7,11]



C164–9

Write Cycle No. 2($\overline{CE}$ Controlled)[7,11,12]



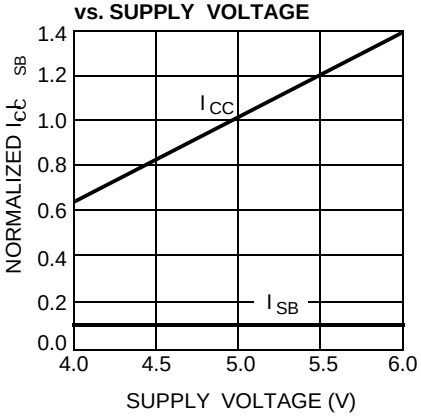
C164–10

Notes:
11. CY7C166 only: Data I/O will be high-impedance if $\overline{OE} = V_{IH}$.
12. If $\overline{CE}$ goes HIGH simultaneously with $\overline{WE}$ HIGH, the output remains in a high-impedance state.

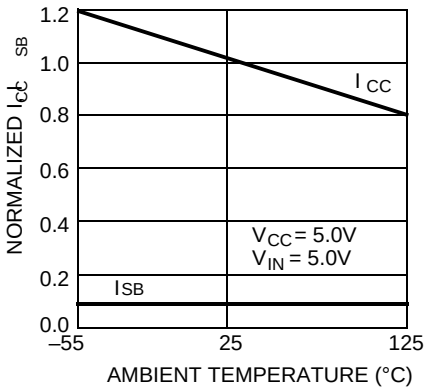
Downloaded from Arrow.com.
[+] Feedback

Typical DC and AC Characteristics

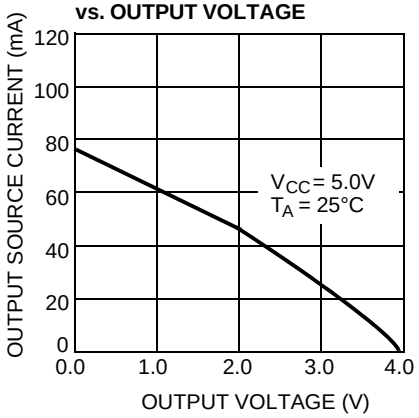
NORMALIZED SUPPLY CURRENT vs. SUPPLY VOLTAGE



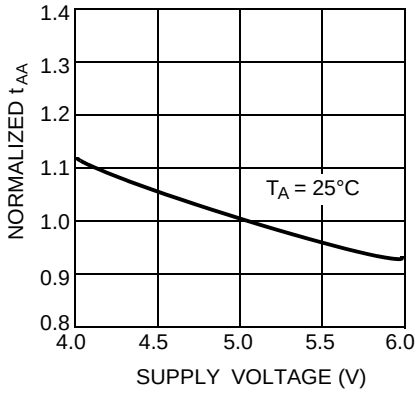
NORMALIZED SUPPLY CURRENT vs. AMBIENT TEMPERATURE



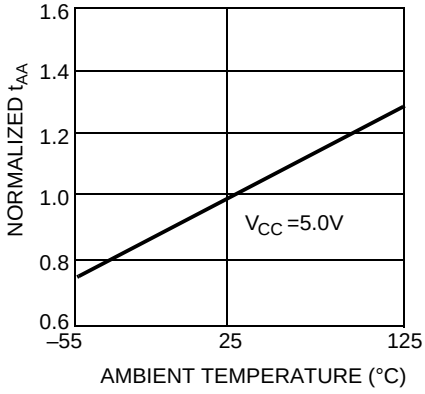
OUTPUT SOURCE CURRENT vs. OUTPUT VOLTAGE



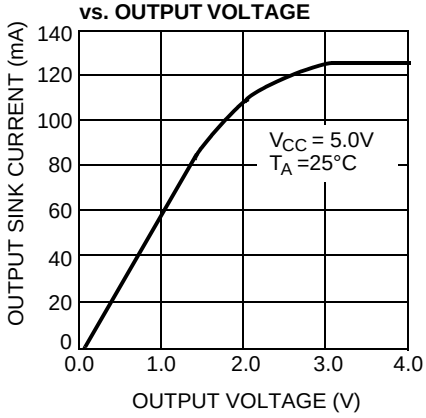
NORMALIZED ACCESS TIME vs. SUPPLY VOLTAGE



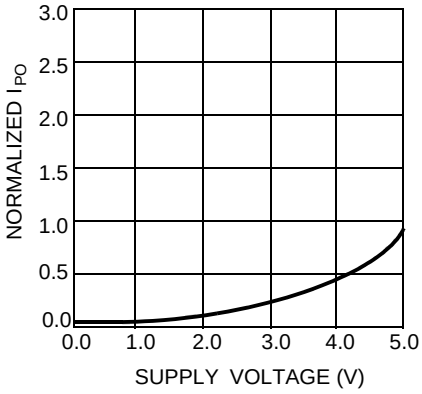
NORMALIZED ACCESS TIME vs. AMBIENT TEMPERATURE



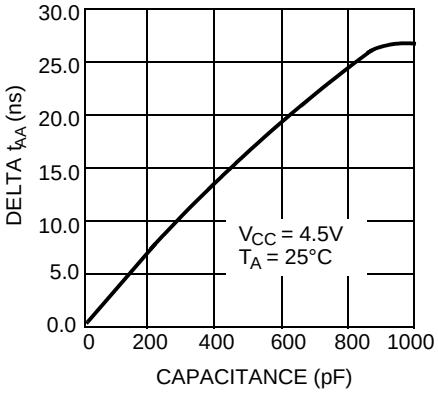
OUTPUT SINK CURRENT vs. OUTPUT VOLTAGE



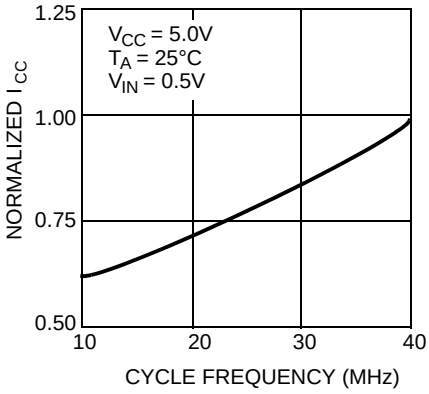
TYPICAL POWER-ON CURRENT vs. SUPPLY VOLTAGE



TYPICAL ACCESS TIME CHANGE vs. OUTPUT LOADING



NORMALIZED I_{CC} vs. CYCLE TIME



Downloaded from Arrow.com.
[+] Feedback

CY7C164 Truth Table

$\overline{CE}$	$\overline{WE}$	Input/Output	Mode	Power
H	X	High Z	Deselect/Power-Down	Standby (I_{SB})
L	H	Data Out	Read	Active (I_{CC})
L	L	Data In	Write	Active (I_{CC})

CY7C166 Truth Table

$\overline{CE}$	$\overline{WE}$	$\overline{OE}$	Input/Output	Mode	Power
H	X	X	High Z	Deselect/Power-Down	Standby (I_{SB})
L	H	L	Data Out	Read	Active (I_{CC})
L	L	H	Data In	Write	Active (I_{CC})
L	H	H	High Z	Select/Output Disabled	Active (I_{CC})

Address Designators

Address Name	Address Function	CY 7C164 Pin Number	CY7C166 Pin Number
A5	X3	1	1
A6	X4	2	2
A7	X5	3	3
A8	X6	4	4
A9	X7	5	5
A10	Y5	6	6
A11	Y4	7	7
A12	Y0	8	8
A13	Y1	9	9
A0	Y2	17	19
A1	Y3	18	20
A2	X0	19	21
A3	X1	20	22
A4	X2	21	23

Ordering Information

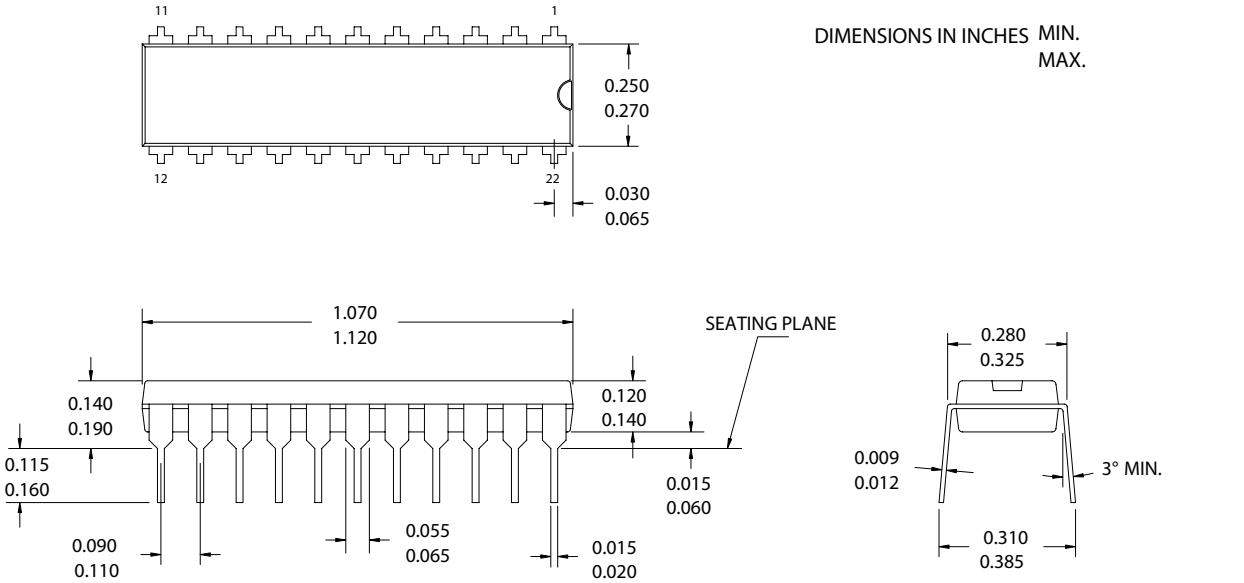
Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
15	CY7C164-15PC	51-85012	22-pin (300-Mil) Molded DIP	Commercial
	CY7C166-15VC	51-85030	24-pin (300-Mil) Molded SOJ	
25	CY7C164-25PC	51-85012	22-pin (300-Mil) Molded DIP	Commercial
	CY7C166-25VC	51-85030	24-pin (300-Mil) Molded SOJ	

Downloaded from Arrow.com.

[+] Feedback

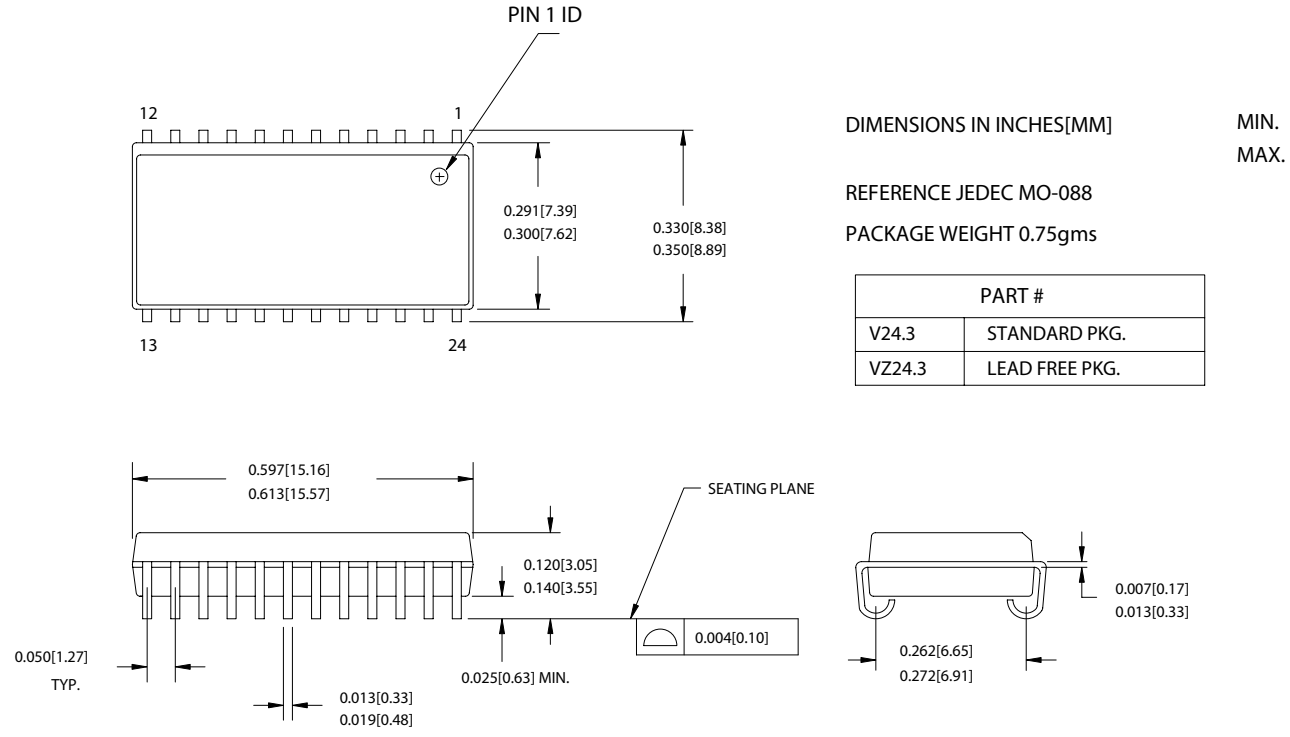
Package Diagrams

22-pin (300-Mil) PDIP (51-85012)



51-85012-*A

24-pin (300-mil) SOJ (51-85030)



PART #	
V24.3	STANDARD PKG.
VZ24.3	LEAD FREE PKG.

51-85030-*B

© Cypress Semiconductor Corporation, 2006. The information contained herein is subject to change without notice. Cypress Semiconductor Corporation assumes no responsibility for the use of any circuitry other than circuitry embodied in a Cypress product. Nor does it convey or imply any license under patent or other rights. Cypress products are not warranted nor intended to be used for medical, life support, life saving, critical control or safety applications, unless pursuant to an express written agreement with Cypress. Furthermore, Cypress does not authorize its products for use as critical components in life-support systems where a malfunction or failure may reasonably be expected to result in significant injury to the user. The inclusion of Cypress

Downloaded from Arrow.com.

[+] Feedback

Document History Page

Document Title: CY7C164/CY7C166 16K x 4 Static RAM Document Number: 38-05025				
REV.	**ECN NO.**	**Issue Date**	**Orig. of Change**	**Description of Change**
**	106811	09/10/01	SZV	Change from Spec number: 38-00032 to 38-05025
*A	486744	See ECN	NXR	Removed 20 ns and 35 ns speed bin from Product offering Removed 24-pin (300-Mil) Molded DIP package Changed the description of I_{IX} from Input Load Current to Input Leakage Current in DC Electrical Characteristics table Removed I_{OS} parameter from DC Electrical Characteristics table Updated the ordering information table

Downloaded from Arrow.com.